NSN 5962-01-195-2284

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View Online at https://aerobasegroup.com/nsn/5962-01-195-2284

Body Length:
Between 1.190 inches and 1.290 inches
Body Width:
0.610 inches
Body Height:
Between 0.090 inches and 0.170 inches
Maximum Power Dissipation Rating:
330.0 milliwatts
Operating Tempurature Range:
55.0/+125.0 degrees celsius
Storage Tempurature Range:
65.0/+150.0 degrees celsius
Features Provided:
Monolithic and bipolar and programmed
nclosure Material:
Ceramic
nclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
nput Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
90.00 nanoseconds propagation delay time, high to low level output and 90.00 nanoseconds propagation delay time, low to high level
putput
Memory Device Type:
Rom
Memory Capacity:
Jnknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Domilitarization:

Yes - demil/mli

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